P lasm on ic electrom agnetically-induced transparency in symmetric structures

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Abstract

A broken symmetry is generally believed to be a prerequisite of plasmonic electrom agneticallyinduced transparency (EIT), since the asymmetry renders the excitation of the otherwise forbidden dark mode possible. Nevertheless, according to the picture of magnetic-plasmon resonance (MPR) mediated plasmonic EIT, we show that the plasmonic EIT can be achieved even in the symmetric structures based on the second-order MPR. This sharpens our understanding of the existing concept, but also a profound insight into the plasmonic coherent interference in the near- eld zone.

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K eyw ords: plasm on ic electrom agnetically-induced transparency, m agnetic plasm on resonance, sym m etry

Electrom agnetically-induced transparency (EIT) is an important quantum interference e ect induced by the interaction between the laser beam s and atom ensembles under twophoton resonance condition.^{1,2,3} This e ect can be applied to quantum communication,⁴ slow-light, and enhanced nonlinear e ects.⁵ C om pared to the EIT of atom ic system, the plasm onic EIT in m etam aterials has the advantages, such as manipulation at room tem – perature, excitation of single optical eld, integration of nanoplasm onic circuits. Therefore, a great deal of attention has been paid to the classical analogue of EIT in m echanical oscillators, RLC circuits,⁶ optical resonators,⁷ optical dipole antennas,^{8,9,10,11} trapped-m ode patterns,¹² split-ring resonators,^{13,14} and array of m etallic nanoparticles.¹⁵

Thanks to this a merging of plasmonics and metamaterials, it is of great perspective to manipulate light at the nanometer scale with metal nanostructures as nano-optical components.^{8,16} The application of optical dipole antennas is a speci c example of this merging among the aforementioned studies on the classical analogue of EIT. Zhang et al.⁸ rst proposed a scheme consisting of bright and dark plasmonic modes that resembles the atom ic system of three levels. Subsequently, it was developed as a tripod system manifesting the classical analogue of quantum coherence swapping.⁹ Recently, Liu et al.¹¹ experimentally demonstrated the plasmonic EIT at the D rude damping limit using a stacked optical metamaterial composed of an upper gold strip and a lower pair of gold strips with a dielectric spacer. It was found that the asymmetry is a prerequisite of plasmonic EIT; otherwise, only a single absorption peak is visible without any sign of an EIT -like e ect. Most of researchers also hold this view^{11,14,17} explicitly or implicitly, since the dark mode is unlikely to be excited if it does not have the broken symmetry.

In this letter we propose a scheme for the generation of plasmonic EIT even in symmetric structures. This scheme is a minor modi cation of the symmetric structure in Ref. 11 that makes the EIT-like e ect available. The underlying origin is also elucidated in detail based on the picture of magnetic-plasmon resonance (MPR) mediated plasmonic EIT.

As described in Ref. 11, each unit cell consists of an upper gold strip as a bright mode and a lower pair of gold strips as a dark mode with a dielectric spacer, as shown in Fig. 1. In particular, the parameters is de ned to depict the lateral displacement. Either the symmetry or the asymmetry is expressed as s = 0 or $s \in 0$, respectively. The plasmonic EIT originates from the coupling of the two modes when the symmetry is broken.^{11,14,20} Essentially, the former serves as an optical dipole antenna, and the latter as a quadrupole

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antenna, when light is illum inated perpendicularly and the electric eld of the light is parallel to the upper strip. Our study is limited to investigation of the symmetric structure, and the similar geometrical parameters are used with two major dimensions. One is that the dielectric spacer and the substrate are not taken into account for simplicity, i.e., they are treated as air, which does not a light is carried to the EIT like feature except for a blueshift. It does not cause any loss of generality in the discussion afterwards. The other is that the lower pair of gold strips is elongated to 790 nm, about two times longer than that in Ref. 11. The reason for this elongation will be explained later. The numerical calculation is carried out by using a nite-integration package, CST M icrowave Studio. The permittivity of gold is described by the D rude model with a plasm on frequency of $!_p = 2 - 2175 - 10^{15}$ rad/s and a collision frequency of $_c = 1.225 - 10^{14}$ Hz, which is three times larger than that in bulk gold.^{11,18}

Figure 2 displays the simulated transmission and absorption spectra for the symmetric structures with the di erent vertical distance h. The latter is calculated according to A = 1T R, where T and R denote the transm ission and the relection, respectively. A stonishingly, the EIT -like feature completely disappears when the length of the lower pair is relatively short, b = 315 nm, without varying the other parameters. In contrast, this feature clearly manifests around 240 THz if the lower pair is elongated to 790 nm without any other variations. In other words, whether the plasm onic E II can be excited or not depends on the length of the lower pair, rather than the structural asymmetry. This appears inconsistent with the conclusion in Ref. 11, where it is believed that the coupling fades away owing to the structural symmetry. Therefore, to solve this puzzle, what the coupling is and how the coupling works must be deciphered. Lu et al.¹⁰ provided a physical picture for plasmonic EIT, in which it is considered as a result of plasm onic coherent interference in near-eld zone based on the excitation of surface plasm on polaritons (SPPs) and MPR. The form er is form ed on the upper strip since it behaves as an optical dipole antenna,¹⁹ while the latter is induced by the magnetic component of dipole elds. A coording to this picture, the disappearance of the EIT -like e ect can be explained by the fact that the magnetic components have the same magnitudes in opposite directions on the both sides of the upper strip if the structure is symmetric and thus the induced currents cancel each other out. Despite their opposite directions, the two magnetic components cannot be equal in the absence of symmetry so as to produce the current or quadrupole in the lower pair. This means that the pivot of the

plasm onic EIT is determined by whether the lower pair (i.e., dark mode) is excited or not.

The point of importance is that the quadrupole can not in general be excited by norm al incidence because of its vanishing dipole m on ent (i.e., it is dark). To activate it, a highly angled illum ination must be resorted to.^{8,20} As shown in Fig. 3, two dark modes were m agnetically excited at 120 and 240 TH z when the plane wave irradiates on the elongated pair (790 nm) along the -y direction, without symmetry breaking of both the incident eld and the structure itself. The latter frequency is twice as high as that of the form er, which can be ascribed to be the second-order M PR.²¹ The second resonant peak at 240 TH z was located coincidentally at the plasm onic EIT peak as shown in Fig. 2. Therefore, on the basis of this physical picture, the lower pair is excited explicitly at 240 TH z.

If we take a closer look at the z-component distribution of the magnetic eld at the frequency of plasm onic EIT, as the physical picture describes, it is unambiguous that the magnetic elds point in and out of x-y plane on both sides of the upper strip [see Fig. 4(a)]. Since there is the fact that the magnetic eld is =2 out of phase with the electric eld,^{10,22} the y-component distribution of the electric eld is illustrated in Fig. 4(b) with a =2 phase di erence compared to the magnetic one, where the dark mode is activated and two antisymmetric quadrupolar resonances are induced on both sides of the upper pair by two antisymmetric magnetic elds of dipole elds. Duo to the excitation of the two circular currents, the plasm onic EIT was also achieved in the symmetric structures. Because the length of the lower pair was elongated, more room is provided to accommodate the two circular currents thereby avoiding canceling each other out. Consequently, the second-order M PR is excited so that the plasm onic EIT can appear even in the symmetric structures (see Fig. 2). This possibility was not even considered as a candidate for plasm onic EIT.

Furtherm ore, as shown in Fig. 3, the intensity of the second-order MPR is larger than that of the fundam ental mode so as to broaden the FW HM of the plasmonic EIT peak compared with that in Ref. 11. It is generally believed that the strongly coupling renders the larger FW HM 13 On the other hand, the strength of the coupling can be tuned by adjusting the vertical distance h. The larger the vertical distance, the smaller the FW HM, of course, at the cost of transmission.

In conclusion, it is possible for the plasmonic EIT to be realized even in symmetric structures. This is determined by whether the MPR can be excited or not, which claries the puzzle of the essence of coupling and strongly validates the mechanism of plasmonic

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EIT. Essentially, symmetry or asymmetry is not the pivot of the plasmonic analogue of EIT, but the MPR is. The resembling modi cation was not carried out on the upper strip at the moment because the frequency scaling law of SPPs is more complicated than that of MPR arising from the phase shift.²³ The point of great interest is that the optical response is invariant, whereas the restrictions on size are partly relaxed, and thus the fabrication is much easier.

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Figure captions

Fig. 1. (a) Three-dimensional view and (b) two-dimensional view of the unit cell. The geometric parameters are w = 80 nm, d = 100 nm, $l_1 = 346 \text{ nm}$, $l_2 = 790 \text{ nm}$, and s = 0. The vertical distance between the upper gold strip and the lower pair of gold strips is denoted to be h and the thickness of each strip, t, is 40 nm. The periods of structure is 870 nm in both the x and y directions. The incident plane wave irradiates along the z direction and its electric component, E, is parallel to the x direction.

Fig. 2. (color online) (a) Transmission and (b) absorption spectra with various vertical distances h. The black curves in (a) and (b) are obtained with the same parameters (h = 70 nm) except $l_2 = 315$ nm.

Fig. 3. (a) Schematics for the incident plane wave on the lower pair of gold strips $(l_2 = 790 \text{ nm})$, where the wave is parallel to the strips and its electric eld along the x direction. The arrow is an E_y probe placed 10 nm away from the center of the end facet. (b) Spectral response of the E_y probe.

Fig. 4. (a) z-component distribution of magnetic eld at the frequency of plasmonic E IT with h = 70 nm, where the phase is 150. (b) The y-component distribution of electric eld at the same frequency, where the phase is 60.



FIG.1: Jin et al.





FIG.2: Jin et al.



FIG.3: Jin et al.





FIG.4: Jin et al.